查询ON2179供应商 捷多邦 Reflective Photosensors (Photo Reflectors)

捷多邦,专业PCB打样工厂,24小时加急

CNZ2179 (ON2179)

Reflective Photosensor

Overview

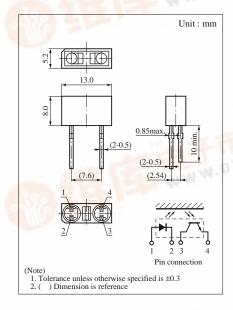
CNZ2179 is a reflective photosensor with a long focal distance, in which a high efficiency GaAs infrared light emitting diode is used as a light emitting element and a high sensitivity Si phototransistor is used as the light detecting element.

Features

- Long focal distance : 6 mm (typ.)
- Visible light cutoff resin is used

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	Symbol	Ratings	Unit	
	Reverse voltage (DC)	V _R	3	V
Input (Light emitting diode)	Forward current (DC)	I _F	50	mA
	Power dissipation	P _D *1	75	mW
192	Collector current	I _C	20	mA
Output (Photo transistor)	Collector to emitter voltage	V _{CEO}	20	V
	Emitter to collector voltage	V _{ECO}	5	V
	Collector power dissipation	P _C *2	100	mW
Temperature	Operating ambient temperature	T _{opr}	-25 to +80	°C
	Storage temperature	T _{stg}	-30 to +85	°C
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Absolute Maximum Ratings ($Ta = 25^{\circ}C$)



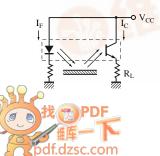
^{*1} Input power derating ratio is 1.25 mW/°C at Ta \geq 25°C.

^{*2} Output power derating ratio is 1.67 mW/°C at Ta $\ge 25^{\circ}$ C.

Electrical Characteristics (Ta = 25°C)

Parameter		Symbol	Conditions	min	typ	max	Unit
Input	Forward voltage (DC)	V _F	$I_F = 50 \text{mA}$		1.3	1.5	V
characteristics	Reverse current (DC)	I _R	$V_R = 3V$			10	μA
Output characteristics	Collector cutoff current	I _{CEO}	$V_{CE} = 10V$. 65	0.2	μA
Transfer	Collector current	I _C *1	$V_{CC} = 5V, I_F = 20mA, R_L = 100\Omega$	180		1500	μΑ
	Response time	t_r^{*2}, t_f^{*3}	$V_{CC} = 10V, I_C = 0.1 \text{mA}, R_L = 100\Omega$	120	20		μs
	Collector to emitter saturation voltage	V _{CE(sat)}	$I_{\rm F} = 50 {\rm mA}, I_{\rm C} = 0.1 {\rm mA}$			0.5	V

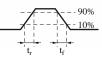
*1 Transfer characteristics measurement circuit (Ambient light is shut off completely.)

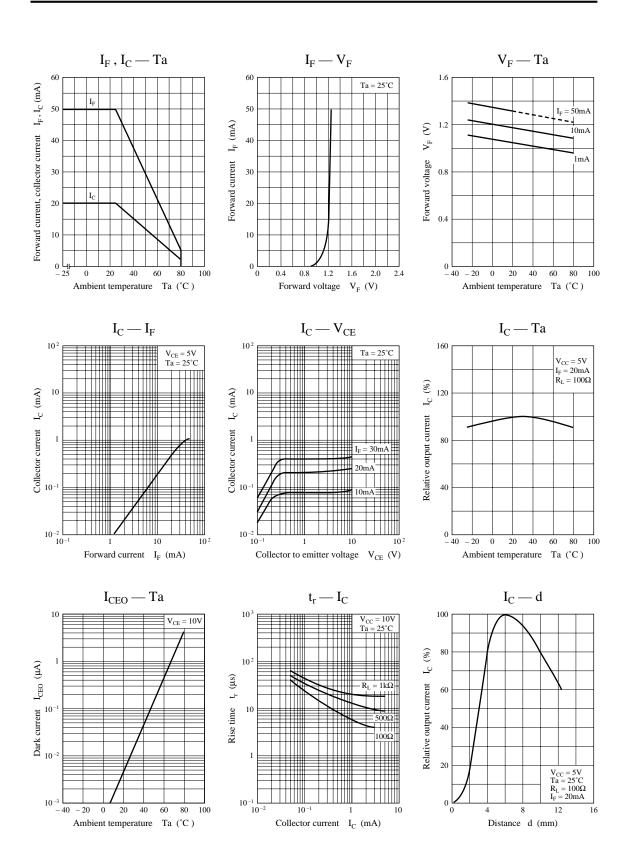


d = 5 mm

Standard white paper (Reflective ratio 90%)

- *2 Time required for the collector current to increase from 10% to 90% of its final value.
- *3 Time required for the collector current to decrease from 90% to 10% of its initial value.





▲ Caution for Safety

Gallium arsenide material (GaAs) is used in this product.

Therefore, do not burn, destroy, cut, crush, or chemically decompose the product, since gallium arsenide material in powder or vapor form is harmful to human health.

Observe the relevant laws and regulations when disposing of the products. Do not mix them with ordinary industrial waste or household refuse when disposing of GaAs-containing products.

Request for your special attention and precautions in using the technical information and semiconductors described in this material

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- Any applications other than the standard applications intended.

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